

# MBR1030CT thru MBR10100CT

## **SCHOTTKY BARRIER RECTIFIERS**

REVERSE VOLTAGE - 30 to 100 Volts FORWARD CURRENT - 10.0 Amperes

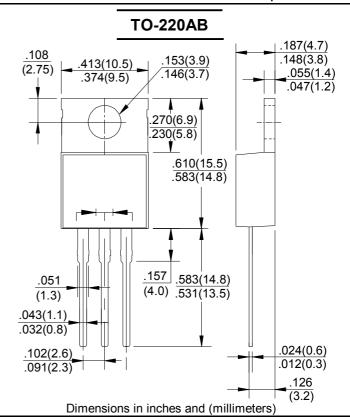
#### **FEATURES**

- Metal of silicon rectifier, majority carrier conduction
- Guard ring for transient protection
- Low power loss, high efficiency
- ●High current capability,low VF
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

## **MECHANICAL DATA**

Case: TO-220AB molded plastic
Polarity: As marked on the body
Weight: 0.08ounces,2.24 grams

Mounting position :Any



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

SYMBOL VRRM	MBR 1030CT 30	MBR 1040CT	MBR 1050CT	MBR 1060CT	MBR 1080CT	MBR 10100CT	UNIT
	30	40				1010001	
Volue		40	50	60	80	100	V
VRIVIS	21	28	35	42	56	70	V
VDC	30	40	50	60	80	100	V
I(AV)	10.0					Α	
IFSM	125					А	
VF	0.70 0.57 0.80 0.70		0.80 0.65 0.90 0.75		0.85 0.75 0.95 0.85		V
lR	0.1 15					mA	
Сл	1	70	2:	20	3	00	pF
Rejc	3.0 3.0			.0	°C/W		
TJ	-55 to +150					$^{\circ}\!\mathbb{C}$	
Tstg	-55 to +175					$^{\circ}\!\mathbb{C}$	
	I(AV)  IFSM  VF  IR  CJ  ReJC  TJ	VDC 30  I(AV)  IFSM  0. 0. 0. IR  CJ 1' Rejc TJ	VDC 30 40  I(AV)  IFSM  0.70 0.57 0.80 0.70  IR  CJ 170  ReJC 3  TJ	VDC 30 40 50  I(AV) 10  IFSM 11  VF 0.57 0.80 0.70 0.  IR 0  CJ 170 22  ReJC 3.0  TJ -55 to	VDC         30         40         50         60           I(AV)         10.0           IFSM         125           VF         0.70         0.80           0.57         0.65           0.80         0.90           0.70         0.75           IR         0.1           TS         15           CJ         170         220           ReJC         3.0           TJ         -55 to +150	VDC         30         40         50         60         80           I(AV)         10.0	VDC         30         40         50         60         80         100           I(AV)         10.0

NOTES:1.300us pulse width,2% duty cycle.

2.Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to case.



